

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	101134	(phase-chang\$3) or (phase near2 changeable) or (phase near2 chang\$5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:29
L2	1633501	memory or memories	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:31
L3	4640	1 same 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:49
L4	2098077	insulat\$3 or dielectric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:49
L5	100945	(top or upper) adj2 (electrode\$1 or conduct\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:50
L6	471195	spacer\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:51
L7	78491	(opening\$1 or opening\$1 or via\$1 or hole\$1) with 6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:56
L8	2749	tip\$1 same 5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:55

L9	117621	(opening\$1 or opening\$1 or via\$1 or hole\$1) with etch\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:56
L10	244	3 and 4 and 9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:56
L11	14	10 and 8 and 7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:57
L12	230	10 not 11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:57
L13	32	3 and 8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:57
L14	18	13 not 10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/15 13:57